Scanning Electron Microscopy (SEM)

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Basic Methods of Materials Analysis

- Look at the Material (Shiny or Dull?)
- Hold Material (Heavy of Light?)
- Taste Material (Surface Chemistry?)
- Bite Material (Ductile ?)
- Drop Test (Brittle ?)
- Put it in a Scanning Electron Microscope (SEM) !
- Other Methods

Large Number of Signals



Scanning Electron Microscope (SEM)



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What is an SEM?



Types of Electron Gun

- Two main types;
 - Thermal
 - Tungsten Filament
 - LaB₆ Filament
 - -Field Emission
 - Cold Field Emission
 - Schottky Field emission gun

The Electron Gun



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Hairpin Tungsten Filament



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Characteristics of Sources

	Units	Tungsten	LaB ₆	FEG
Operating Temperature	K	2700	1700	300
Current Density	A/m ²	5x10 ⁴	10 ⁶	10 ¹⁰
Crossover size	μm	50	10	<0.01
Energy spread	eV	3	1.5	0.3
Stability	% / hr	<1	<1	5
Vacuum	Pa	10 -2	10 -4	10 -8
Lifetime	hr	100	500	>1000

Magnetic lens



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Secondary Electron Detector



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Backscattered Electron Detector



SEM: Electron Detectors





Backscattered Electron Image

Secondary Electron Image

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Brief History of SEM

- 1935 Knoll Scanning TEM
- 1942 RCA Labs, Zworykin
- 1948 Cambridge University C. W. Oatley
- 1963 Pease, SEM V became Cambridge Scientific Instruments Mark 1 Stereoscan
- 1960 Everhart and Thornley : development of the SE Detector

Why SEM ?

- Good resolution
- Large magnification range 20x 20000x or more
- Depth of field
- 3-D Information (perspective)
- Easy to use
- Easy sample preparation
- Lots of uses and applications
- Great deal of information obtainable on one instrument
- Reasonable cost (purchase and operating)
- Ubiquitous

SEM Flavors



Environmental Scanning Electron Microscope (ESEM)



ESEM : Quanta 200



•CIMS Contact : Dr. Richard Schalek

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ESEM Example: Salt Water Diatom



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ESEM Example: Silicon Nanowires



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ESEM: In situ Experiments



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SEM FAB Applications



SEM FAB Applications





Hitachi RS-3000 Defect Review SEM

Raith 150 Ultra High Precision E-Beam Lithography and Metrology System

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Focused Ion Beam System



FEI D235 DualBeam FIB/SEM

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FEI D235 DualBeam FIB/SEM



- Focused Ion Beam (with liquid Ga source) can scan and etch
- Or with injected gas cause deposition (metals, dielectrics)
- CIMS Contact : Dr. Warren MoberlyChan

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SEM Based Materials Analysis



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EDX and WDS analysis

- Electron Microprobe
 - Combines EDX and WDS analysis
 - SEM Column
 - Typically Tungsten
 Filament
 - Optimized for microanalysis



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EDX Spectrum and Mapping



EDX Analysis Mapping



SEM Mapping Image Ni/Fe Meteorite







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Electron backscattered Diffraction (EBSP or EBSD)



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EBSP – Fundamentals

- SEM based technique
 - 70° tilted specimen
 - 1-10 nA , ~20 kV
- Detector
 - Phosphor + CCD camera
- EBSP
 - Kikuchi bands (planes)
 - Zones (directions)
- Orientation
 - Sub-micron resolution
 - ~0.5deg angular resolution
- Surface Effect
 - Sampling upper 30-50nm
 - Surface prep important!

Courtesy Tim Maitland, HKL Technology



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EBSP: System Diagram



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What does an EBSP look like?



$Silicon \ at \ 20 kV \qquad {\rm Courtesy} \ {\rm Tim} \ {\rm Maitland}, {\rm HKL} \ {\rm Technology}$

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How it works - EBSP formation

- The Electron beam strikes the • specimen
- Scattering produces electrons • travelling in all directions in a small volume (the excitation volume)
- Electrons that travel in a direction • that satisfies the Bragg condition $(n\lambda = 2d_{hkl}.sin\theta)$ for a plane (hkl) are channeled \Rightarrow Kikuchi bands
- The electrons hit the imaging • phosphor and produce light
- The light is detected by a CCD • camera and converted to an image

Courtesy Tim Maitland, HKL Technology

Which is indexed... •



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EBSP: Indexing Cycle



EBSP: Visualization of Data

General Microstructure

Deformed silica (quartz)



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Pixel map of pattern quality + crystal orientation + grain boundary location and character

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SEM Operating Considerations

- Effects of Accelerating Voltage
 - Sample charging
 - Resolution / Image quality
- Effects of aperture size
 - Depth of Field and Resolution
- Working distance
 - Depth of Field and Resolution
- Tilting the sample
 - Understanding the Geometry
- Effect of Probe size/current
- Astigmatism

Imaging



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Effects of Accelerating Voltage



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Effects of Accelerating Voltage: Example



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Sample Interaction Volume with Voltage



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Working Distance



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Working Distance: Example



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Aperture Size



Tilting the Sample



- Important
- Understand the geometry of the sample
- Understand the geometry of the detector

Tilting the Sample / Geometry



- Tilting is important
- Two or Three different tilt angles
- Pull back to capture overall view and to understand geometry

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Imaging Considerations



- Seeing is not believing
- Image interpretation is important
- Beware of image artifacts
- Beware of sample/detector geometry effects
- Beware !!!

Demonstration: Using Web SEM





JEOL 5910 SEM running Web SEM from CMSE MIT

Specimen

Courtesy of Anthony J. Garratt-Reed

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SEM Instrument Considerations for Nanostructure Imaging

- In the lens secondary electron detector
- Field emission electron gun
 Cold emission (Better ?)
- High vacuum or UHV system – Minimize contamination

In the Lens SE Detector



In the Lens SE Detector Example



Standard SE Detector

In Lens SE Detector

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4mm

In the Lens SE Detector Example



Standard SE Detector

In Lens SE Detector

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In-Lens SE Detector Example



Standard SE Detector

In Lens SE Detector

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Some Examples SEM Imaged Nanostructures

- Materials Comparisons
- Structure Examination
- Silicon Nanowires
- Coatings
- Fabrication
- Nano Machines
- Nano Arrays
- Carbon Nanotubes

Example: Materials Comparisons



3DOM: Composition: CaO (20 mol%) - P2O5 (4 mol%) - SiO2 (76 mol%)

Sol-Gel Process

Diatom: Stephanodiscus Niagarae (ME184) Composition: SiO2 + small Ca

Phase Separation Process

Example: Diatoms



Stephanodiscus Niagarae (ME184)

Sample Courtesy of Mark Edlund, St. Croix Watershed Research Station

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Example: Si Nanowires



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Example: Si Nanowires



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Example: Optical Coatings Au on SiC



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Example: Cross Sections



Example: Nano Array



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Example: Nano Array



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Example: Nano Machines Failure Mode Analysis



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Example: Chromite



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Example: SnO on Sn



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Example: Carbon Nanotube Spheres



200µm 100X



10µm 2000X

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Example: Nanotube Spheres





2µm 12000X



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Example: Carbon Nanotubes



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Example: Carbon Nanotubes



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Example: Carbon Nanotubes



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SEM : Nanostructures Imaging Checklist

- General SEM Considerations
 - Low beam voltage
 - Small apertures
 - Small working distance
 - Minimal sample coatings (if any)
 - Precise adjustment of astigmatism
- Instrument Considerations
 - In the lens SE Detector
 - Cold Field Emission Electron Gun
 - High Vacuum or UHV System

CIMS SEM Instruments



LEO A SEM



LEO B SEM



Cameca Microprobe



Quanta 200 ESEM



FEI D235 Dual Beam FIB/SEM

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